

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Janice Nickel
Serial No. : Not Assigned
Filed: Not Assigned

Docket No.: 10991744-4
Group Art Unit: Not Assigned
Examiner: Not Assigned

Title: MRAM Device Including Spin Dependent Tunneling Junction Memory Cells
{As Amended herein}

A Divisional of: Janice Nickel
Serial No. : 09/514,934
Filed: 02/08/2000

Docket No.: 10991744-1
Group Art Unit: 2823
Examiner: Neal Berezny

Title: Method of Fabricating an MRAM Device Including Spin Dependent Tunneling Junction Memory Cells

PRELIMINARY AMENDMENT AND RESPONSE UNDER 37 C.F.R. §1.115

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

Please consider this Divisional Application in light of the following preliminary amendments and remarks.

Please amend the above application as follows: